

# MMBD2835LT1G, MMBD2836LT1G, SMMD2835LT1G

## Monolithic Dual Switching Diodes

### Features

- AEC-Q101 Qualified and PPAP Capable
- S Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant\*

### MAXIMUM RATINGS (EACH DIODE)

Rating	Symbol	Value	Unit
Reverse Voltage MMBD2835LT1G, SMMD2835LT1G MMBD2836LT1G	$V_R$	35 75	Vdc
Forward Current	$I_F$	100	mAdc

### THERMAL CHARACTERISTICS

Total Device Dissipation FR-5 Board (Note 1) $T_A = 25^\circ\text{C}$ Derate above $25^\circ\text{C}$	$P_D$	225	mW
		1.8	mW/ $^\circ\text{C}$
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	556	$^\circ\text{C}/\text{W}$
Total Device Dissipation Alumina Substrate, (Note 2) $T_A = 25^\circ\text{C}$ Derate above $25^\circ\text{C}$	$P_D$	300	mW
		2.4	mW/ $^\circ\text{C}$
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	417	$^\circ\text{C}/\text{W}$
Junction and Storage Temperature	$T_J, T_{stg}$	-55 to +150	$^\circ\text{C}$

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

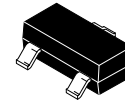
1. FR-5 =  $1.0 \times 0.75 \times 0.062$  in.
2. Alumina =  $0.4 \times 0.3 \times 0.024$  in. 99.5% alumina.

\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

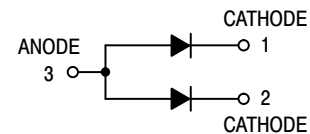


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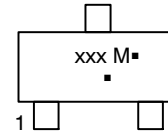
<http://onsemi.com>



SOT-23 (TO-236AB)  
CASE 318-08  
STYLE 12



### MARKING DIAGRAM



xxx = Specific Device Code  
A3X = MMBD2835LT1G  
SMMD2835LT1G  
A2X = MMBD2836LT1G  
M = Date Code  
■ = Pb-Free Package  
(Note: Microdot may be in either location)

\*Date Code orientation and/or overbar may vary depending upon manufacturing location.

### ORDERING INFORMATION

Device	Package	Shipping†
MMBD2835LT1G	SOT-23 (Pb-Free)	3,000 / Tape & Reel
SMMD2835LT1G	SOT-23 (Pb-Free)	3,000 / Tape & Reel
MMBD2836LT1G	SOT-23 (Pb-Free)	3,000 / Tape & Reel

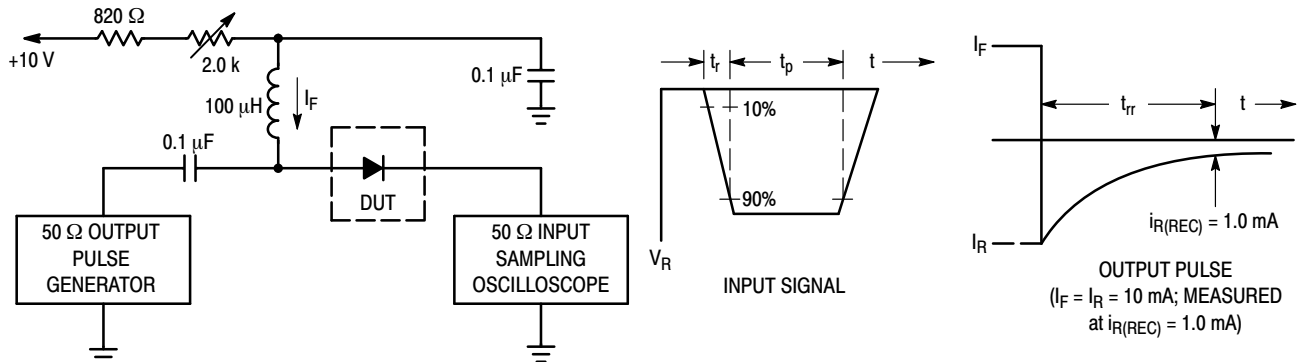
†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

# MMBD2835LT1G, MMBD2836LT1G, SMMBD2835LT1G

## ELECTRICAL CHARACTERISTICS ( $T_A = 25^\circ\text{C}$ unless otherwise noted) (EACH DIODE)

Characteristic	Symbol	Min	Max	Unit
<b>OFF CHARACTERISTICS</b>				
Reverse Breakdown Voltage ( $I_R = 100 \mu\text{Adc}$ ) MMBD2835LT1G, SMMBD2835LT1G MMBD2836LT1G	$V_{(BR)}$	35 75	- -	Vdc
Reverse Voltage Leakage Current (Note 3) ( $V_R = 30 \text{Vdc}$ ) MMBD2835LT1G, SMMBD2835LT1G ( $V_R = 50 \text{Vdc}$ ) MMBD2836LT1G	$I_R$	- -	100 100	nAdc
Diode Capacitance ( $V_R = 0 \text{V}$ , $f = 1.0 \text{MHz}$ )	$C_T$	-	4.0	pF
Forward Voltage ( $I_F = 10 \text{mAdc}$ ) ( $I_F = 50 \text{mAdc}$ ) ( $I_F = 100 \text{mAdc}$ )	$V_F$	- - -	1.0 1.0 1.2	Vdc
Reverse Recovery Time ( $I_F = I_R = 10 \text{mAdc}$ , $I_{R(REC)} = 1.0 \text{mAdc}$ ) (Figure 1)	$t_{rr}$	-	4.0	ns

3. For each individual diode while the second diode is unbiased.



- Notes: 1. A 2.0 kΩ variable resistor adjusted for a Forward Current ( $I_F$ ) of 10 mA.  
 2. Input pulse is adjusted so  $I_{R(\text{peak})}$  is equal to 10 mA.  
 3.  $t_p \gg t_{rr}$

**Figure 1. Recovery Time Equivalent Test Circuit**

# MMBD2835LT1G, MMBD2836LT1G, SMMBD2835LT1G

## CURVES APPLICABLE TO EACH CATHODE

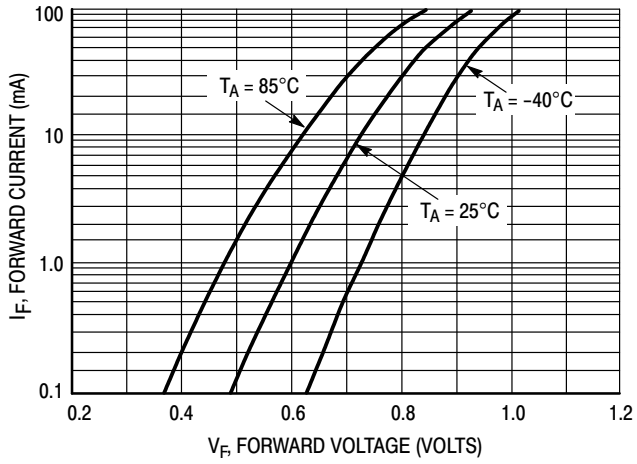


Figure 2. Forward Voltage

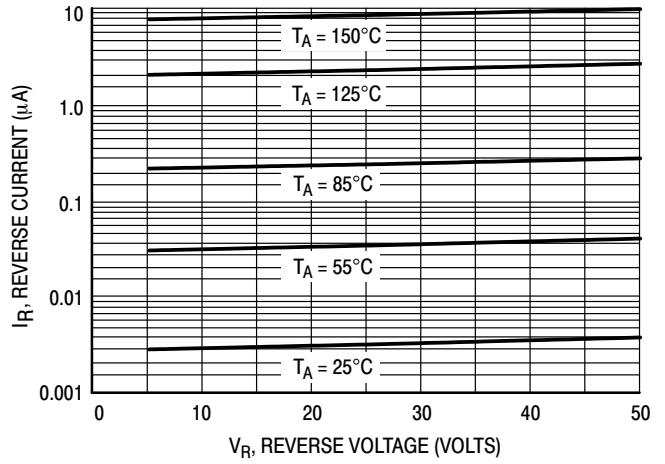


Figure 3. Leakage Current

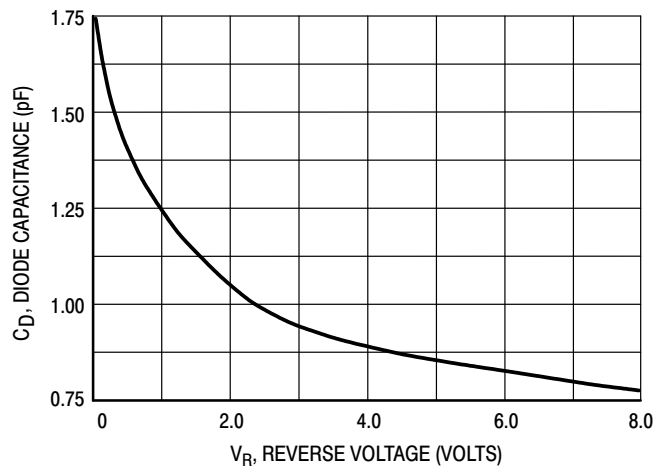


Figure 4. Capacitance

# MMBD2835LT1G, MMBD2836LT1G, SMMBD2835LT1G

## PACKAGE DIMENSIONS

SOT-23 (TO-236)  
CASE 318-08  
ISSUE AP



NOTES:

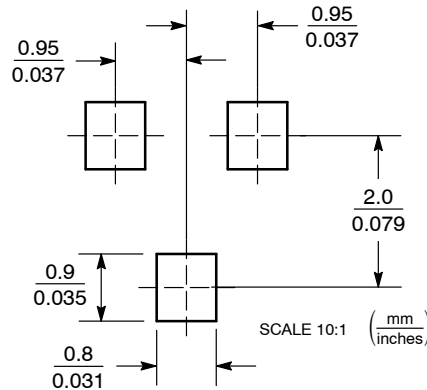
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
4. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

DIM	MILLIMETERS			INCHES		
	MIN	NOM	MAX	MIN	NOM	MAX
A	0.89	1.00	1.11	0.035	0.040	0.044
A1	0.01	0.06	0.10	0.001	0.002	0.004
b	0.37	0.44	0.50	0.015	0.018	0.020
c	0.09	0.13	0.18	0.003	0.005	0.007
D	2.80	2.90	3.04	0.110	0.114	0.120
E	1.20	1.30	1.40	0.047	0.051	0.055
e	1.78	1.90	2.04	0.070	0.075	0.081
L	0.10	0.20	0.30	0.004	0.008	0.012
L1	0.35	0.54	0.69	0.014	0.021	0.029
HE	2.10	2.40	2.64	0.083	0.094	0.104
θ	0°	---	10°	0°	---	10°

STYLE 12:

1. CATHODE
2. CATHODE
3. ANODE

### SOLDERING FOOTPRINT



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